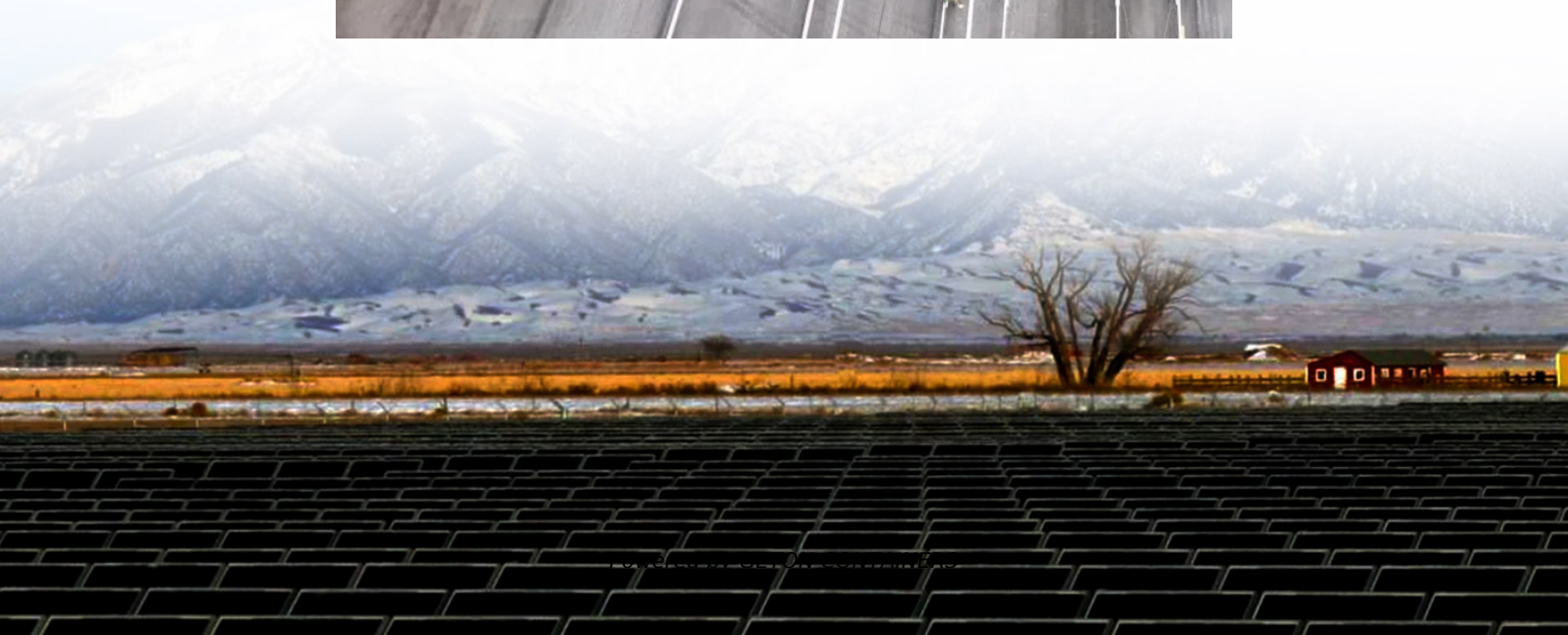
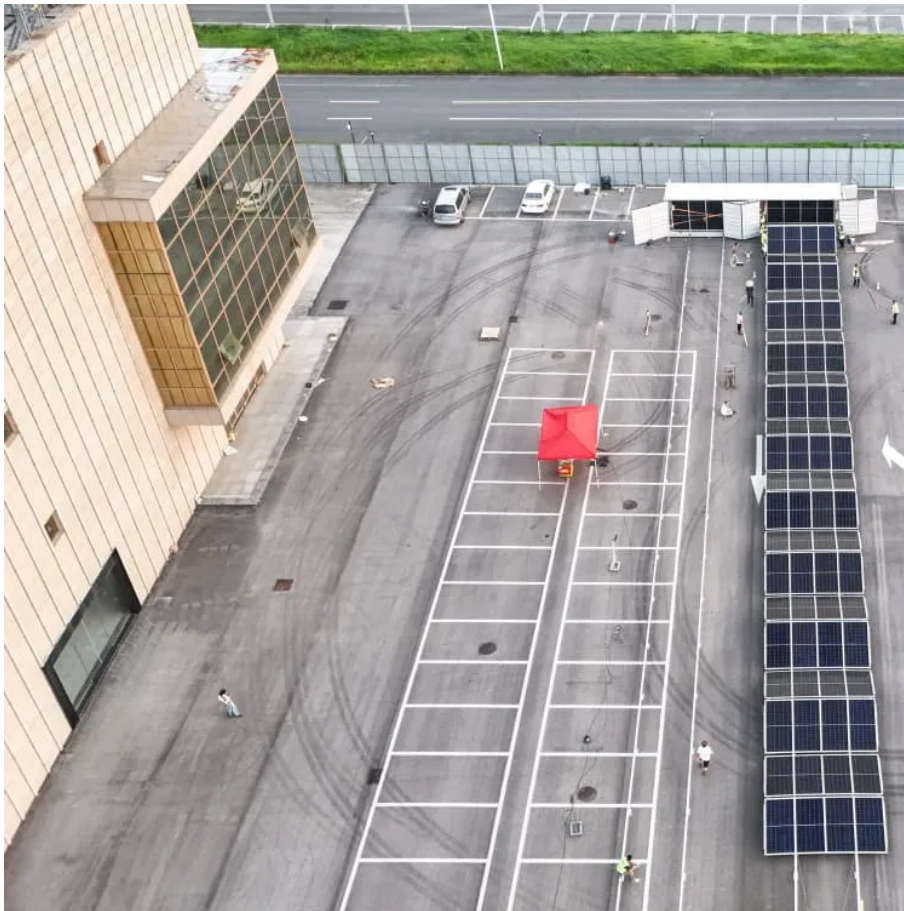


Amorphous inverter low power





Overview

What is the power consumption of EM circuit with the proposed inverter?

The power consumption of the EM circuit with the proposed inverter is measured at the low values from 0.836 mW to 0.568 mW over pulse widths from 3 to 2157 horizontal times. It is ensured that the proposed circuit achieves the low power consumption regardless of pulse widths. 1. Introduction.

How to achieve low power consumption?

The low power consumption is achieved by avoiding the shoot-through current paths through an optimized inverter circuit. The proposed circuit consists of 12 TFTs and 2 capacitors including 6 TFTs and 1 capacitor for the inverter circuit to control the pulling-down TFTs.

Should em drivers contain inverters?

Therefore, the EM drivers should contain inverters [31, 32] to keep the pulling-down TFTs turned off stably during the high pulse generation, where the inverters composed of one-type TFTs may increase power consumption proportionally to the pulse width .

What is a good voltage for an inverter?

In addition, the inverters demonstrate superior performance at a relevant supply voltage (VDD) of 1.5 V: voltage gain exceeding 10 V/V, noise margin over 80%, picowatt-range static-power consumption, and near-ideal switching voltage of half-VDD.



Amorphous inverter low power



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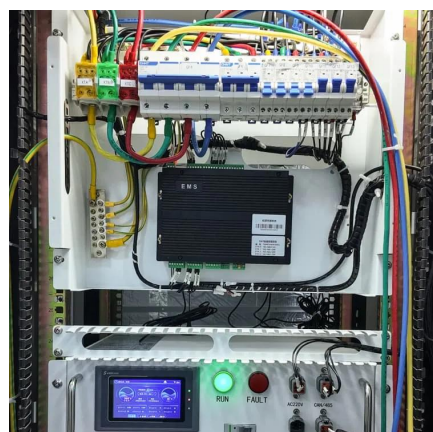
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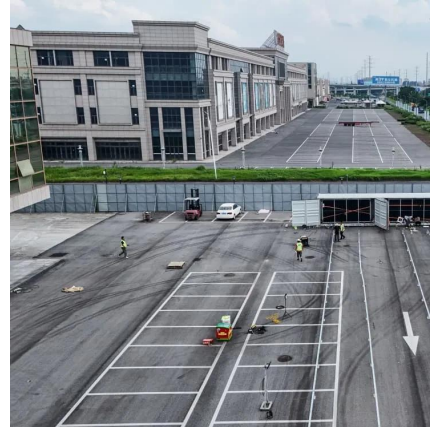
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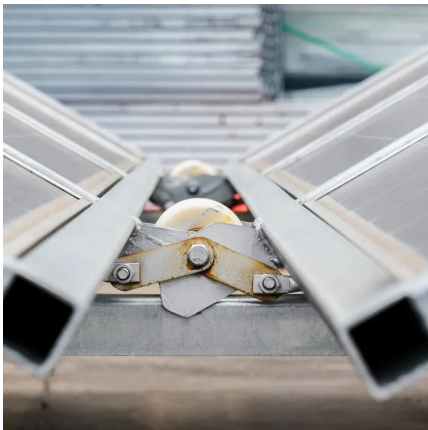
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